

First Named Inventor	Frankie F. Roohparvar	<p align="center">INFORMATION DISCLOSURE STATEMENT</p>
Serial No.	Unknown	
Filing Date	Filed herewith	
Group Art Unit	Unknown	
Examiner Name	Unknown	
Confirmation No.	Unknown	
Attorney Docket No.	400.044US02	
<p>Title: SYNCHRONOUS FLASH MEMORY WITH ACCESSIBLE PAGE DURING WRITE</p>		

Commissioner for Patents
M.S.: Patent Application
P. O. Box 1450
Alexandria, VA 22313-1450

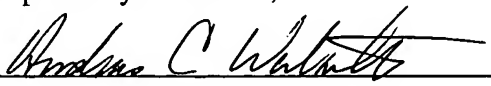
In compliance with 37 C.F.R. §§ 1.56 and 1.97, *et seq.*, the enclosed materials are brought to the attention of the Examiner for consideration in connection with the above-identified Application. Applicant respectfully requests that this Information Disclosure Statement be entered and the references listed on the attached Form 1449 be considered by the Examiner and made of record. Pursuant to MPEP §609, Applicant further requests that the Examiner initial next to each reference on the Form 1449 to indicate that the listed references have been considered. Applicant further requests that a copy of the initialed Form 1449 be returned with the next official communication.

Further pursuant to MPEP §609, because all of the references listed on the attached Form 1449 have been previously submitted and made of record in the parent application, U.S. Patent Application 09/627,770, filed July 28, 2000, copies of the references previously made of record in the parent application are not submitted herewith.

If the Examiner has any questions or concerns regarding this application, please contact the undersigned at the number listed below.

Date: 3/11/04

Respectfully submitted,


Andrew C. Walseth
Reg. No. 43,234

Attorneys for Applicant
Leffert Jay & Polglaze, P.A.
P.O. Box 581009
Minneapolis, MN 55458-1009

T – 612/312-2200
F – 612/312-2250

Applicant(s)	Frankie Roohparvar	INFORMATION DISCLOSURE STATEMENT FORM PTO-1449
Serial No.	Unknown	
Filing Date	Filed Herewith	
Group Art Unit	Unknown	
Examiner Name	Unknown	
Attorney Docket No.	400.044US02	
Title: SYNCHRONOUS FLASH MEMORY WITH ACCESSIBLE PAGE DURING WRITE		

Sheet 1 of 1

U.S. Patent References				
Examiner Initials	Patent No.	Issue Date	Name	Filing Date
	5,041,886	08/20/91	Lee	09/25/89
	5,537,354	07/16/96	Mochizuki et al.	12/14/94
	5,600,605	02/04/97	Schaefer	06/07/95
	5,657,292	08/12/97	McClure	01/19/96
	5,666,321	09/09/97	Schaefer	09/01/95
	5,732,017	03/24/98	Schumann et al.	03/31/97
	5,751,039	05/12/98	Kauffman et al.	09/19/97
	5,787,457	07/28/98	Miller et al.	10/18/96
	5,808,946	09/15/98	Roohparvar	03/27/97
	5,867,430	02/02/99	Chen et al.	12/20/96
	5,889,727	03/30/99	Hsu et al.	05/11/98
	5,913,928	06/22/99	Morzano	06/22/99
	5,936,903	08/10/99	Jeng et al.	08/07/98
	5,995,438	11/30/99	Jeng, et al.	08/07/98
	6,026,465	02/15/00	Mills et al.	06/18/97
	6,077,211	06/20/00	Vo	02/27/98
	6,137,133	10/24/00	Kauffman et al.	05/11/98
	6,141,247	10/31/00	Roohparvar et al.	12/21/98
	6,240,040	05/29/01	Akaogi et al.	03/15/00
	6,418,506	07/09/02	Pashley et al.	12/31/96

Foreign Patent References					
Examiner Initials	Foreign Patent		Name	Publication Date	T?
	Country	No.			
	JP	H8-221312	Hitachi Ltd.	08/30/96	

Other References	
Examiner Initials	Author, Title, Date, Pages, etc.
	Keeth, et al., "DRAM circuit design: a tutorial," IEEE Press, 2001, pp.16-23, 142-153
	Micron Semiconductor Products, Inc., "2Mb, Smart 5 BIOS-Optimized Boot Block Flash Memory," <u>Flash Memory</u> www.micron.com, copyright 2000, Micron Technology, Inc., pp. 1-12
	Micron, "16 Mb: x16 SDRAM" <u>Synchronous DRAM</u> , www.micron.com, copyright 1999 Micron Technology, Inc., pp. 1-51

Examiner Signature		Date Considered	
*Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.			